LT1468



FEATURES

- 90MHz Gain Bandwidth, f = 100kHz
- 22V/µs Slew Rate
- Settling Time: 900ns (A_V = -1, 150µV, 10V Step)
- Low Distortion, –96.5dB for 100kHz, 10V_{P-P}
- Maximum Input Offset Voltage: 75µV
- Maximum Input Offset Voltage Drift: 2µV/°C
- Maximum (–) Input Bias Current: 10nA
- Minimum DC Gain: 1000V/mV
- Minimum Output Swing into 2k: ±12.8V
- Unity Gain Stable
- Input Noise Voltage: 5nV/√Hz
- Input Noise Current: 0.6pA/√Hz
- Total Input Noise Optimized for 1k < R_S < 20k</p>
- Specified at ±5V and ±15V

APPLICATIONS

- 16-Bit DAC Current-to-Voltage Converter
- Precision Instrumentation
- ADC Buffer
- Low Distortion Active Filters
- High Accuracy Data Acquisition Systems
- Photodiode Amplifiers

90MHz, 22V/µs 16-Bit Accurate Operational Amplifier **DESCRIPTION**

The LT®1468 is a precision high speed operational amplifier with 16-bit accuracy and 900ns settling to 150μ V for 10V signals. This unique blend of precision and AC performance makes the LT1468 the optimum choice for high accuracy applications such as DAC current-to-voltage conversion and ADC buffers. The initial accuracy and drift characteristics of the input offset voltage and inverting input bias current are tailored for inverting applications.

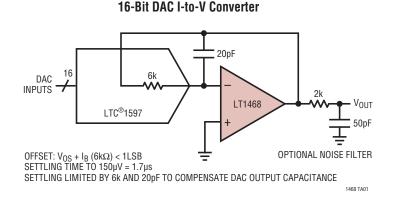
The 90MHz gain bandwidth ensures high open-loop gain at frequency for reducing distortion. In noninverting applications such as an ADC buffer, the low distortion and DC accuracy allow full 16-bit AC and DC performance.

The 22V/µs slew rate of the LT1468 improves large-signal performance in applications such as active filters and instrumentation amplifiers compared to other precision op amps.

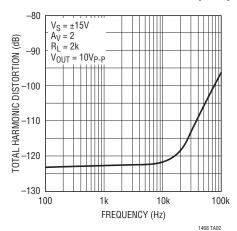
The LT1468 is manufactured on a complementary bipolar process. It is available in a space saving 3mm × 3mm lead-less package, as well as small outline and DIP packages.

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TYPICAL APPLICATION

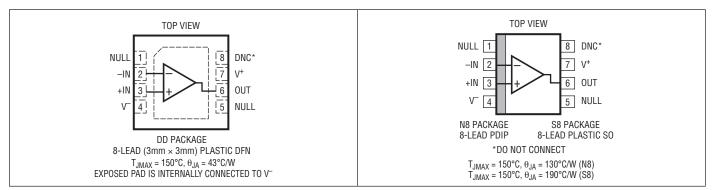


Total Harmonic Distortion vs Frequency



ABSOLUTE MAXIMUM RATINGS (Note 1)

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT1468CN8#PBF	NA	LT1468CN8	8-Lead PDIP	0°C to 70°C
LT1468IN8#PBF	NA	LT1468IN8	8-Lead PDIP	-40°C to 85°C
LT1468CS8#PBF	LT1468CS8#TRPBF	1468	8-Lead Plastic Small Outline	0°C to 70°C
LT1468IS8#PBF	LT1468IS8#TRPBF	14681	8-Lead Plastic Small Outline	-40°C to 85°C
LT1468ACDD#PBF	LT1468ACDD#TRPBF	LDJX	8-Lead (3mm × 3mm) Plastic DFN	0°C to 70°C
LT1468AIDD#PBF	LT1468AIDD#TRPBF	LDJX	8-Lead (3mm × 3mm) Plastic DFN	-40°C to 85°C
LT1468CDD#PBF	LT1468CDD#TRPBF	LDJX	8-Lead (3mm × 3mm) Plastic DFN	0°C to 70°C
LT1468IDD#PBF	LT1468IDD#TRPBF	LDJX	8-Lead (3mm × 3mm) Plastic DFN	-40°C to 85°C
LEAD BASED FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT1468CN8	NA	LT1468CN8	8-Lead PDIP	0°C to 70°C
LT1468IN8	NA	LT1468IN8	8-Lead PDIP	-40°C to 85°C
LT1468CS8	LT1468CS8#TR	1468	8-Lead Plastic Small Outline	0°C to 70°C
LT1468IS8	LT1468IS8#TR	14681	8-Lead Plastic Small Outline	–40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/



ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{CM} = 0V unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	V _{SUPPLY}	MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage	N8, S8	±15V ±5V		30 50	75 175	μV μV
		LT1468A, DD Package	±15V ±5V		30 50	75 175	μV μV
		LT1468, DD Package	±15V ±5V		100 150	200 300	μV μV
l _{os}	Input Offset Current		±5V to ±15V		13	50	nA
I _B -	Inverting Input Bias Current		±5V to ±15V		3	±10	nA
I_B^+	Noninverting Input Bias Current		±5V to ±15V		-10	±40	nA
	Input Noise Voltage	0.1Hz to 10Hz	±5V to ±15V		0.3		μV _{P-P}
e _n	Input Noise Voltage	f = 10kHz	±5V to ±15V		5		nV/√Hz
i _n	Input Noise Voltage	f = 10kHz	±5V to ±15V		0.6		pA/√Hz
R _{IN}	Input Resistance	V _{CM} = ±12.5V Differential	±15V ±15V	100 50	240 150		MΩ kΩ
CIN	Input Capacitance		±15V		4		pF
	Input Voltage Range +		±15V ±5V	12.5 2.5	13.5 3.5		V V
	Input Voltage Range –		±15V ±5V		-14.3 -4.3	-12.5 -2.5	V V
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 12.5V$ $V_{CM} = \pm 2.5V$	±15V ±5V	96 96	110 112		dB dB
PSRR	Power Supply Rejection Ratio	V _S = ±4.5V to ±15V		100	112		dB
A _{VOL}	Large-Signal Voltage Gain	$V_{OUT} = \pm 12.5V, R_{L} = 10k$ $V_{OUT} = \pm 12.5V, R_{L} = 2k$ $V_{OUT} = \pm 2.5V, R_{L} = 10k$ $V_{OUT} = \pm 2.5V, R_{L} = 2k$	±15V ±15V ±5V ±5V	1000 500 1000 500	9000 5000 6000 3000		V/mV V/mV V/mV V/mV
V _{OUT}	Output Swing		±15V ±15V ±5V ±5V	±13.0 ±12.8 ±3.0 ±2.8	±13.6 ±13.5 ±3.6 ±3.5		V V V V
I _{OUT}	Output Current	$V_{OUT} = \pm 12.5V$ $V_{OUT} = \pm 2.5V$	±15V ±5V	±15 ±15	±22 ±22		mA mA
I _{SC}	Short-Circuit Current	$V_{OUT} = 0V, V_{IN} = \pm 0.2V$	±15V	±25	±40		mA
SR	Slew Rate	$A_V = -1, R_L = 2k$ (Note 5)	±15V ±5V	15 11	22 17		V/µs V/µs
	Full-Power Bandwidth	10V Peak, (Note 6) 3V Peak, (Note 6)	±15V ±5V		350 900		kHz kHz
GBW	Gain Bandwidth	$f = 100 kHz, R_L = 2k$	±15V ±5V	60 55	90 88		MHz MHz
THD	Total Harmonic Distortion	$A_V = 2, V_0 = 10V_{P-P}, f = 1kHz$ $A_V = 2, V_0 = 10V_{P-P}, f = 100kHz$	±15V ±15V		0.00007 0.0015		% %
t _r , t _f	Rise Time, Fall Time	A _V = 1, 10% to 90%, 0.1V	±15V ±5V		11 12		ns ns
	Overshoot	A _V = 1, 0.1V	±15V ±5V		30 35		% %
	Propagation Delay	A _V = 1, 50% V _{IN} to 50% V _{OUT} , 0.1V	±15V ±5V		9 10	_	ns ns



ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{CM} = 0V unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	V _{SUPPLY}	MIN	ТҮР	MAX	UNITS
t _s	Settling Time	10V Step, 0.01%, $A_V = -1$ 10V Step, 150µV, $A_V = -1$ 5V Step, 0.01%, $A_V = -1$	±15V ±15V ±5V		760 900 770		ns ns ns
R ₀	Output Resistance	$A_V = 1, f = 100 kHz$	±15V		0.02		Ω
I _S	Supply Current		±15V ±5V		3.9 3.6	5.2 5.0	mA mA

The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $0^{\circ}C \le T_A \le 70^{\circ}C$, $V_{CM} = 0V$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	V _{SUPPLY}		MIN	ТҮР	MAX	UNITS
V _{0S}	Input Offset Voltage	N8, S8	±15V ±5V	•			150 250	μV μV
		LT1468A, DD Package	±15V ±5V	•			150 250	μV μV
		LT1468, DD Package	±15V ±5V	•			300 400	μV μV
	Input V _{OS} Drift	(Note 7)	±5V to ±15V	٠		0.7	2.0	μV/°C
l _{os}	Input Offset Current		±5V to ±15V	•			65	nA
	Input Offset Current Drift		±5V to ±15V			60		pA/°C
I _B -	Inverting Input Bias Current		±5V to ±15V	٠			±15	nA
	Negative Input Current Drift		±5V to ±15V			40		pA/°C
I _B +	Noninverting Input Bias Current		±5V to ±15V	٠			±50	nA
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 12.5V$ $V_{CM} = \pm 2.5V$	±15V ±5V	•	94 94			dB dB
PSRR	Power Supply Rejection Ratio	$V_{\rm S} = \pm 4.5 V \text{ to } \pm 15 V$		٠	98			dB
A _{VOL}	Large-Signal Voltage Gain	$ \begin{array}{l} V_{OUT} = \pm 12.5 V, \ R_L = 10 k \\ V_{OUT} = \pm 12.5 V, \ R_L = 2 k \\ V_{OUT} = \pm 2.5 V, \ R_L = 10 k \\ V_{OUT} = \pm 2.5 V, \ R_L = 2 k \end{array} $	±15V ±15V ±5V ±5V	•	500 250 500 250			V/mV V/mV V/mV V/mV
V _{OUT}	Output Swing	$R_L = 10k$ $R_L = 2k$ $R_L = 10k$ $R_L = 10k$ $R_L = 2k$	±15V ±15V ±5V ±5V	• • •	±12.9 ±12.7 ±2.9 ±2.7			V V V V
I _{OUT}	Output Current	$V_{OUT} = \pm 12.5V$ $V_{OUT} = \pm 2.5V$	±15V ±5V	•	±12.5 ±12.5			mA mA
I _{SC}	Short-Circuit Current	$V_{OUT} = 0V, V_{IN} = \pm 0.2V$	±15V	•	±17			mA
SR	Slew Rate	$A_V = -1, R_L = 2k$ (Note 5)	±15V ±5V	•	13 9			V/µs V/µs
GBW	Gain Bandwidth	f = 100kHz, R _L = 2k	±15V ±5V	•	55 50			MHz MHz
I _S	Supply Current		±15V ±5V	•			6.5 6.3	mA mA





ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $-40^{\circ}C \le T_A \le 85^{\circ}C$, $V_{CM} = 0V$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	VSUPPLY		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage	N8, S8	±15V ±5V	•			230 330	μV μV
		LT1468A, DD Package	±15V ±5V	•			230 330	μV μV
		LT1468, DD Package	±15V ±5V	•			400 500	μV μV
	Input V _{OS} Drift	(Note 7)	±5V to ±15V	•		0.7	2.5	μV/°C
l _{os}	Input Offset Current		±5V to ±15V	٠			80	nA
	Input Offset Current Drift		±5V to ±15V			120		pA/°C
I _B -	Inverting Input Bias Current		±5V to ±15V	٠			±30	nA
	Negative Input Current Drift		±5V to ±15V			80		pA/°C
I _B +	Noninverting Input Bias Current		±5V to ±15V	٠			±60	nA
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 12.5V$ $V_{CM} = \pm 2.5V$	±15V ±5V	•	92 92			dB dB
PSRR	Power Supply Rejection Ratio	V _S = ±4.5V to ±15V		•	96			dB
A _{VOL}	Large-Signal Voltage Gain	$ \begin{array}{l} V_{OUT} = \pm 12V, \ R_L = 10k \\ V_{OUT} = \pm 10V, \ R_L = 2k \\ V_{OUT} = \pm 2.5V, \ R_L = 10k \\ V_{OUT} = \pm 2.5V, \ R_L = 2k \end{array} $	±15V ±15V ±5V ±5V	• • •	300 150 300 150			V/mV V/mV V/mV V/mV
V _{OUT}	Output Swing		±15V ±15V ±5V ±5V	• • •	±12.8 ±12.6 ±2.8 ±2.6			V V V V
I _{OUT}	Output Current	$V_{OUT} = \pm 12.5V$ $V_{OUT} = \pm 2.5V$	±15V ±5V	•	±7 ±7			mA mA
I _{SC}	Short-Circuit Current	$V_{OUT} = 0V, V_{IN} = \pm 0.2V$	±15V	•	±12			mA
SR	Slew Rate	$A_V = -1, R_L = 2k$ (Note 5)	±15V ±5V	•	9 6			V/µs V/µs
GBW	Gain Bandwidth	f = 100kHz, R _L = 2k	±15V ±5V	•	45 40			MHz MHz
I _S	Supply Current		±15V ±5V	•			7.0 6.8	mA mA

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

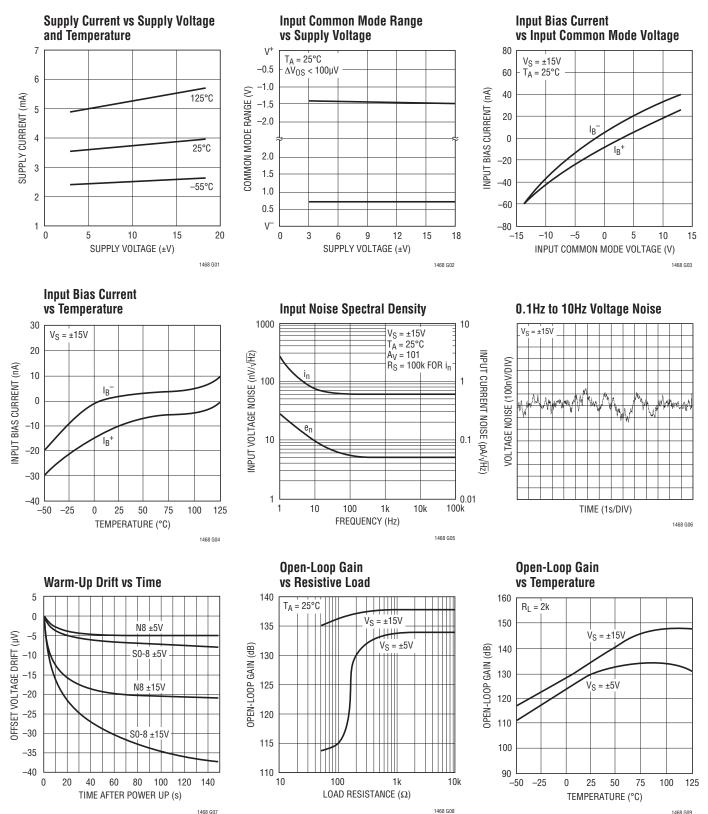
Note 2: The inputs are protected by back-to-back diodes and two 100Ω series resistors. If the differential input voltage exceeds 0.7V, the input current should be limited to 10mA. Input voltages outside the supplies will be clamped by ESD protection devices and input currents should also be limited to 10mA.

Note 3: A heat sink may be required to keep the junction temperature below absolute maximum when the output is shorted indefinitely.

Note 4: The LT1468C is guaranteed to meet specified performance from 0°C to 70°C and is designed, characterized and expected to meet these extended temperature limits, but is not tested at -40° C and at 85°C. The LT1468I is guaranteed to meet the extended temperature limits.

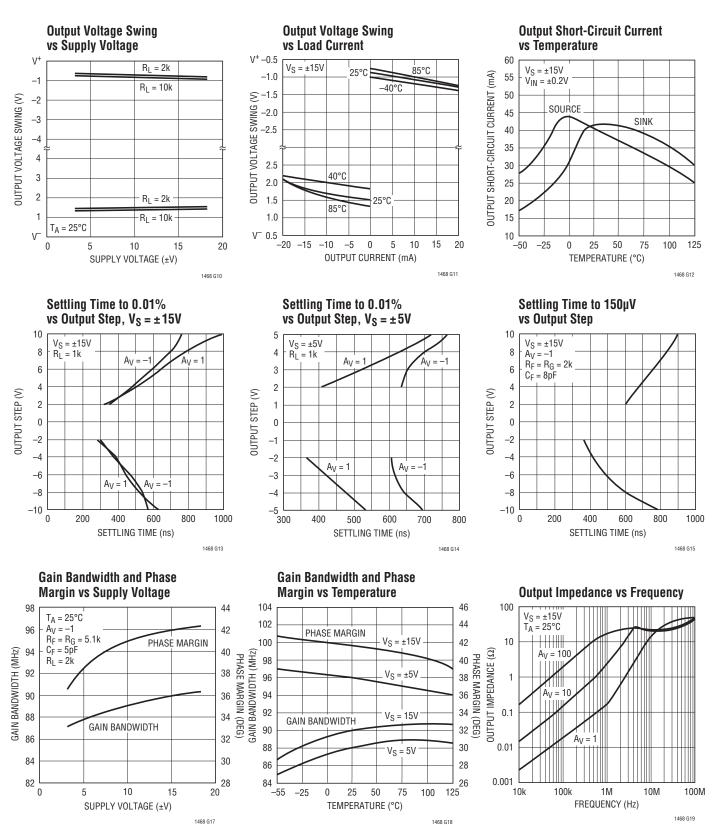
Note 5: Slew rate is measured between ±8V on the output with ±12V input for ±15V supplies and ±2V on the output with ±3V input for ±5V supplies. Note 6: Full power bandwidth is calculated from the slew rate measurement: FPBW = SR/ $2\pi V_P$

Note 7: This parameter is not 100% tested.



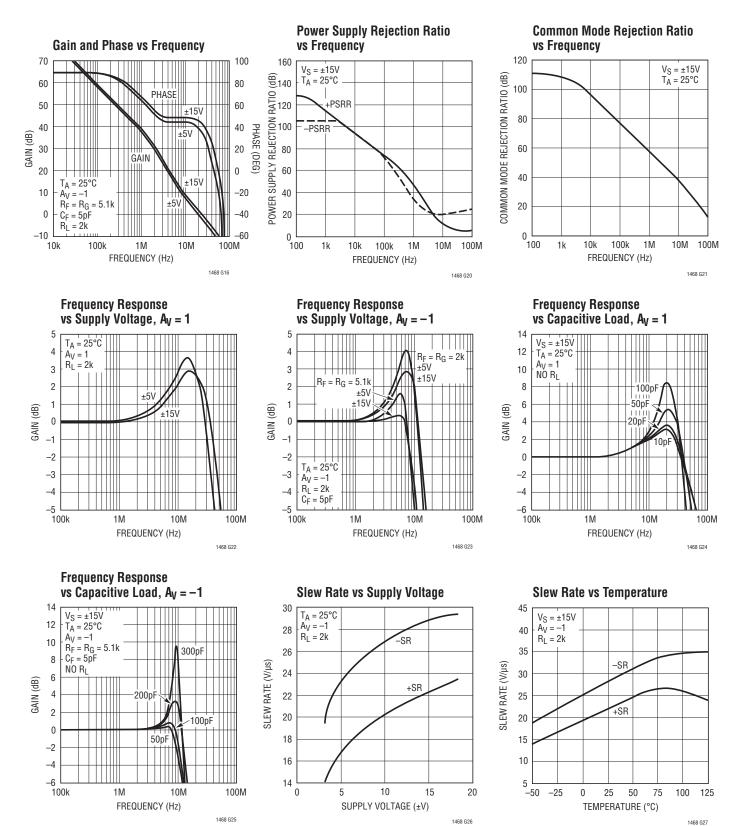
¹⁴⁶⁸ G09



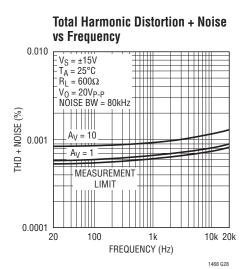


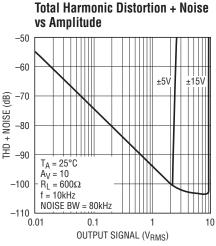


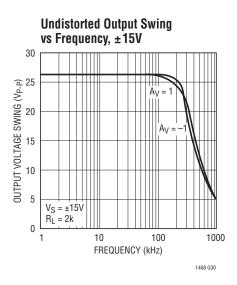




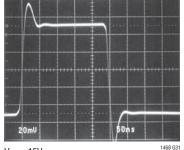








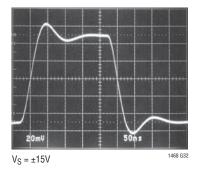
Small-Signal Transient, $A_V = 1$



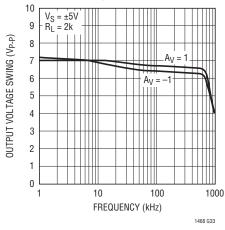
 $V_{S} = \pm 15V$

Small-Signal Transient, $A_V = -1$

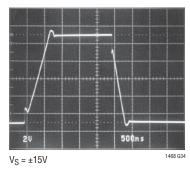
1468 G29

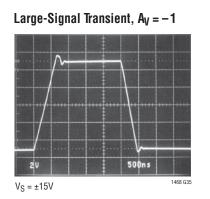


Undistorted Output Swing vs Frequency, ±5V

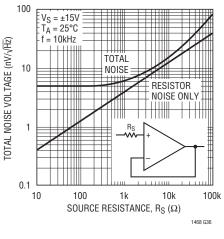


Large-Signal Transient, A_V = 1





Total Noise vs Unmatched Source Resistance



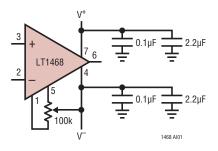




APPLICATIONS INFORMATION

The LT1468 may be inserted directly into many operational amplifier applications improving both DC and AC performance, provided that the nulling circuitry is removed. The suggested nulling circuit for the LT1468 is shown below.

Offset Nulling



Layout and Passive Components

The LT1468 requires attention to detail in board layout in order to maximize DC and AC performance. For best AC results (for example fast settling time) use a ground plane, short lead lengths, and RF-quality bypass capacitors (0.01μ F to 0.1μ F) in parallel with low ESR bypass capacitors (1μ F to 10μ F tantalum). For best DC performance, use "star" grounding techniques, equalize input trace lengths and minimize leakage (i.e., $1.5G\Omega$ of leakage between an input and a 15V supply will generate 10nA—equal to the maximum I_B^- specification.)

Board leakage can be minimized by encircling the input circuitry with a guard ring operated at a potential close to that of the inputs. For inverting configurations tie the ring to ground, in noninverting connections tie the ring to the inverting input (note the input capacitance will increase which may require a compensating capacitor as discussed below.)

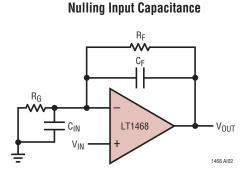
Microvolt level error voltages can also be generated in the external circuitry. Thermocouple effects caused by temperature gradients across dissimilar metals at the contacts to the inputs can exceed the inherent drift of the amplifier. Air currents over device leads should be minimized, package leads should be short, and the two input leads should be as close together as possible and maintained at the same temperature.

Make no connection to Pin 8. This pin is used for factory trim of the inverting input current.

The parallel combination of the feedback resistor and gain setting resistor on the inverting input can combine with the input capacitance to form a pole that can cause peaking or even oscillations. For feedback resistors greater than 2k, a feedback capacitor of the value:

 $C_F > (R_G)(C_{IN}/R_F)$

should be used to cancel the input pole and optimize dynamic performance. For applications where the DC noise gain is one, and a large feedback resistor is used, C_F should be greater than or equal to C_{IN} . An example would be a DAC I-to-V converter as shown on the front page of this data sheet where the DAC can have many tens of pF of output capacitance. Another example would be a gain of -1 with 5k resistors; a 5pF to 10pF capacitor should be added across the feedback resistor. The frequency response in a gain of -1 is shown in the Typical Performance curves with 2k and 5.1k resistors with a 5pF feedback capacitor.





APPLICATIONS INFORMATION

Input Considerations

Each input of the LT1468 is protected with a 100Ω series resistor and back-to-back diodes across the bases of the input devices. If the inputs can be pulled apart, the input current should be limited to less than 10mA with an external series resistor. Each input also has two ESD clamp diodes—one to each supply. If an input is driven above the supply, limit the current with an external resistor to less than 10mA.

The LT1468 employs bias current cancellation at the inputs. The inverting input current is trimmed at zero common mode voltage to minimize errors in inverting applications such as I-to-V converters. The noninverting input current is not trimmed and has a wider variation and therefore a larger maximum value. As the input offset current can be greater than either input current, the use of balanced source resistance is NOT recommended as it actually degrades DC accuracy and also increases noise.

The input bias currents vary with common mode voltage as shown in the Typical Performance Characteristics. The cancellation circuitry was not designed to track this common mode voltage because the settling time would have been adversely affected.

The LT1468 inputs can be driven to the negative supply and to within 0.5V of the positive supply without phase reversal. As the input moves closer than 0.5V to the positive supply, the output reverses phase.

Total Input Noise

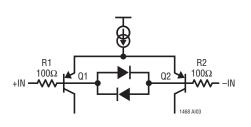
The curve of Total Noise vs Unmatched Source Resistance in the Typical Performance Characteristics shows that with source resistance below 1k, the voltage noise of the amplifier dominates. In the 1k to 20k region the increase in noise is due to the source resistance. Above 20k the input current noise component is larger than the resistor noise.

Capacitive Loading

The LT1468 drives capacitive loads of up to 100pF in unity gain and 300pF in a gain of -1. When there is a need to drive a larger capacitive load, a small series resistor should be inserted between the output and the load. In addition, a capacitor should be added between the output and the inverting input as shown in Driving Capacitive Loads.

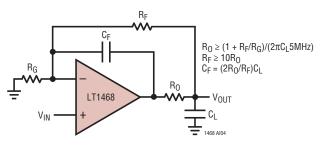
Settling Time

The LT1468 is a single stage amplifier with an optimal thermal layout that leads to outstanding settling performance. Measuring settling, even at the 12-bit level is very challenging, and at the 16-bit level requires a great deal of subtlety and expertise. Fortunately, there are two excellent Linear Technology reference sources for settling measurements, Application Notes 47 and 74. Appendix B of AN47 is a vital primer on 12-bit settling measurements, and AN74 extends the state of the art while concentrating on settling time with a 16-bit current output DAC input.



Input Stage Protection

Driving Capacitive Loads



TECHNOLOGY

APPLICATIONS INFORMATION

The 150μ V settling curve in the Typical Performance Characteristics is measured using the Differential Amplifier method of AN74 followed by a clamped, nonsaturating gain of 100. The total gain of 500 allows a resolution of 100μ V/DIV with an oscilloscope setting of 0.05V/DIV

The settling of the DAC I-to-V converter on the front page was measured using the exact methods of AN74. The optimum nulling of the DAC output capacitance requires 20pF across the 6k feedback resistor. The theoretical limit for 16-bit settling is 11.1 times this RC time constant or 1.33 μ s. The actual settling time is 1.7 μ s at the output of the LT1468. The LT1468 is the fastest Linear Technology amplifier in this application.

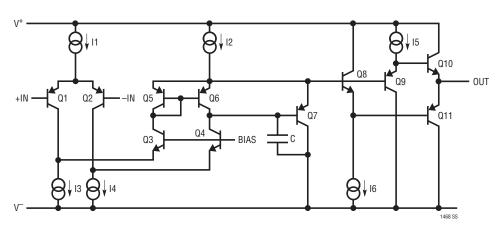
The optional noise filter adds a slight delay of 100ns, but reduces the noise bandwidth to 1.6MHz which increases the output resolution for 16-bit accuracy.

Distortion

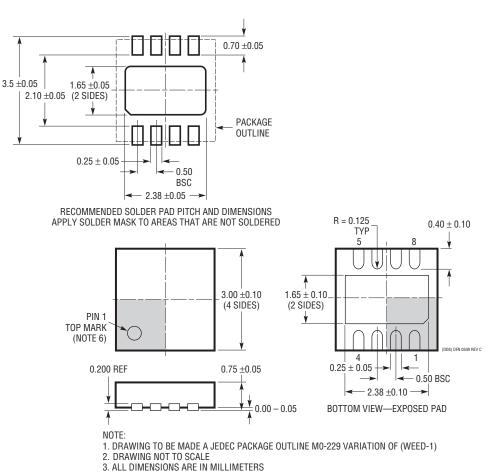
The LT1468 has outstanding distortion performance as shown in the Typical Performance curves of Total Harmonic Distortion + Noise vs Frequency and Amplitude. The high open-loop gain and inherently balanced architecture reduce errors to yield 16-bit accuracy to frequencies as high as 100kHz. An example of this performance is the Typical Application titled 100kHz Low Distortion Bandpass Filter. This circuit is useful for cleaning up the output of a high performance signal generator such as the B & K type 1051 or HP3326A.

Another key application for LT1468 is buffering the input to a 16-bit A/D converter. In a gain of 1 or 2 this straightforward circuit provides uncorrupted AC and DC levels to the converter, while buffering the A/D input sampleand-hold circuit from high source impedance which can reduce the maximum sampling rate. The front page graph shows better than 16-bit distortion for a gain of 2 with a $10V_{P-P}$ output.

SIMPLIFIED SCHEMATIC



PACKAGE DESCRIPTION



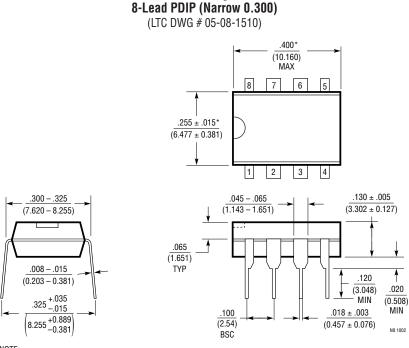
DD Package 8-Lead Plastic DFN ($3mm \times 3mm$) (Reference LTC DWG # 05-08-1698 Rev C)

- ALL DIMENSIONS ARE IN MILLIMETERS
 DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
 EXPOSED PAD SHALL BE SOLDER PLATED
 SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION

ON TOP AND BOTTOM OF PACKAGE



PACKAGE DESCRIPTION



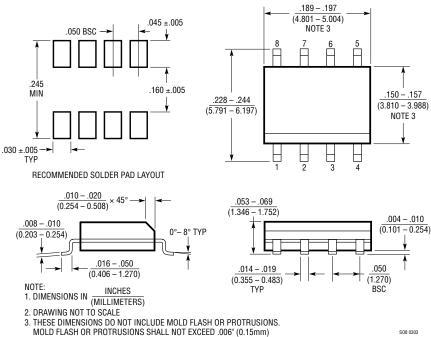
N8 Package

NOTE: 1. DIMENSIONS ARE MILLIMETERS

*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

S8 Package 8-Lead Plastic Small Outline (Narrow 0.150) (LTC DWG # 05-08-1610)





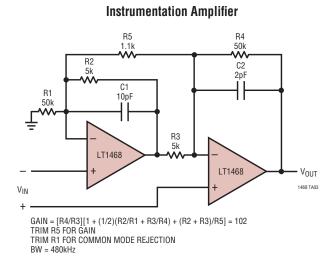
REVISION HISTORY (Revision history begins at Rev B)

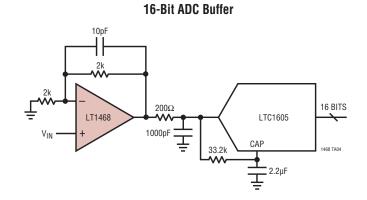
REV	DATE	DESCRIPTION	PAGE NUMBER
В	10/09	Change to Both Packages in Pin Configuration	2



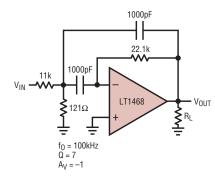
15

TYPICAL APPLICATIONS





100kHz Low Distortion Bandpass Filter



SIGNAL LEVEL	RL	2ND HARMONIC	3RD HARMONIC
1V _{RMS}	1M	-106dB	-103dB
2V _{RMS}	1M	-105dB	-105dB
3.5V _{RMS}	1M	-106dB	-104dB
1V _{RMS}	2k	-103dB	-103dB
2V _{RMS}	2k	-99dB	-103dB
3.5V _{RMS}	2k	-96.5dB	-102dB

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1167	Precision Instrumentation Amplifier	Single Resistor Gain Set, 0.04% Max Gain Error, 10ppm Max Gain Nonlinearity
LTC1595/LTC1596	16-Bit Serial Multiplying I _{OUT} DACs	±1LSB Max INL/DNL, Low Glitch, DAC8043 16-Bit Upgrade
LTC1597	16-Bit Parallel Multiplying I _{OUT} DAC	±1LSB Max INL/DNL, Low Glitch, On-Chip Bipolar Resistors
LTC1604	16-Bit, 333ksps Sampling ADC	±2.5V Input, SINAD = 90dB, THD = -100dB
LTC1605	Single 5V, 16-Bit, 100ksps Sampling ADC	Low Power, ±10V Inputs, Parallel/Byte Interface
LT1469	Dual 90MHz 16-Bit Accurate Op Amp	Dual Version of LT1468
LT1800	80MHz, 25V/µs Low Power Rail-to-Rail Precision Op Amp	$V_{S} \le \pm 5$ V, I_{CC} = 1.6mA, $V_{OS} \le 350 \mu$ V
LT6220	60MHz, 20V/µs Low Power Rail-to-Rail Precision Op Amp	$V_S \le \pm 5 V$, I_{CC} = 0.9mA, $V_{OS} \le 350 \mu V$
LT1722	200MHz, 70V/µs Low Noise Precision Op Amp	$V_S \le \pm 5V$, $e_n = 3.8 \text{nV} / \sqrt{\text{Hz}}$, -85dBc at 1MHz
LTC6244HV	Dual 50MHz, Low Noise, Precision CMOS Op Amp	$V_{S} \le \pm 5V$, $V_{OS} \le 100 \mu$ V, $I_{B} \le 75 pA$



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